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Hyperfast Rectifier, 60 A FRED Pt[®] G5



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)} per leg	60 A				
V _R	600 V				
V _F at I _F at 125 °C	1.2 V				
t _{rr} (typ.)	29				
I _{FSM}	500				
T _J max.	175 °C				
Package	TO-247AD 3L				
Circuit configuration	Single				

FEATURES

- Hyperfast and optimized Qrr
- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature FREE
- · Polyimide passivation
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV battery charging stations and high frequency stages of UPS applications.

MECHANICAL DATA

Case: TO-247AD 3L Molding compound meets UL 94 V-0 flammability rating Terminal: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Repetitive peak reverse voltage	V _{RRM}		600	V		
Average rectified forward current	I _{F(AV)}	T _C = 110 °C, D = 0.50	60			
Non-repetitive peak surge current	I _{FSM}	$T_{C} = 25 \text{ °C}, t_{p} = 10 \text{ ms}, \text{ sine wave}$ both anodes, (1) and (3) connected	500	А		
Repetitive peak forward current	I _{FRM}	T _C = 110 °C, D = 0.50, f = 20 kHz	120			
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C		

ELECTRICAL SPECIFICATIONS ($T_J = 25 \text{ °C}$ unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	600	-	-			
Forward voltage	V _F	I _F = 60 A	-	1.4	1.7	V		
		I _F = 60 A, T _J = 125 °C	-	1.2	-			
De construit de construit	I _R	$V_{R} = V_{R}$ rated	-	-	25			
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA		
Junction capacitance	CT	V _R = 200 V	-	65	-	pF		
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH		

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RoHS COMPLIANT HALOGEN

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		I _F = 1.0 A, dI _F /dt =	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$		29	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	49	-	ns	
		T _J = 125 °C		-	74	-		
Poak rocovery current	1	T _J = 25 °C	I _F = 40 A dI _F /dt = 1000 A/µs	-	21	-	А	
Peak recovery current	I _{RRM}	T _J = 125 °C	$V_{\rm R} = 400 \text{ V}$	-	43	-		
	0	T _J = 25 °C		-	640	-	nC	
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1979	-		
Deverse receiver time		T _J = 25 °C		-	54	-	ns	
Reverse recovery time	t _{rr}	T _J = 125 °C		-	82	-		
Dools recovery ourrent		T _J = 25 °C	I _F = 60 A dI _F /dt = 1000 A/μs V _R = 400 V	-	22	-	A	
Peak recovery current	I _{RRM}	T _J = 125 °C		-	47	-		
D	0	T _J = 25 °C		-	790	-	nC	
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	2385	-	nc	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Thermal resistance, junction-to-case	R _{thJC}		-	-	0.63	°C/W	
Weight			-	5.5	-	g	
			-	0.2	-	oz.	
Mounting torque			6 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Marking device		Case style TO-247AD 3L	A5PH6006L				

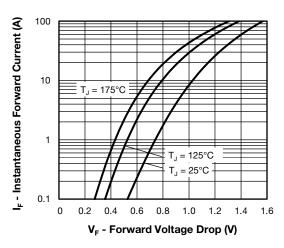


Fig. 1 - Typical Forward Voltage Drop Characteristics

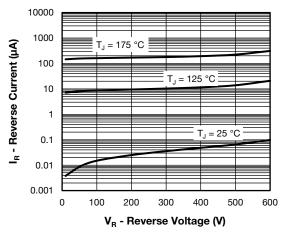


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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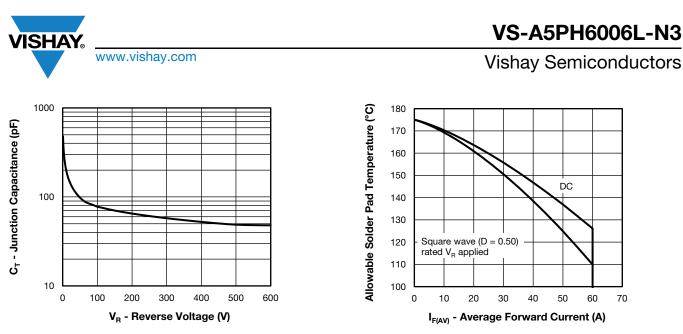


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

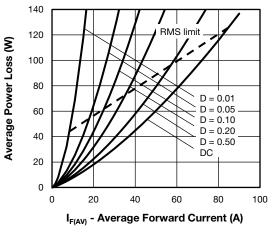


Fig. 5 - Average Power Loss vs. Average Forward Current

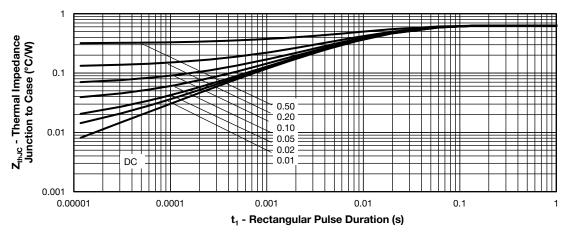


Fig. 6 - Thermal Impedance Z_{thJC} Characteristics

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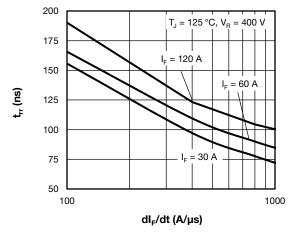


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

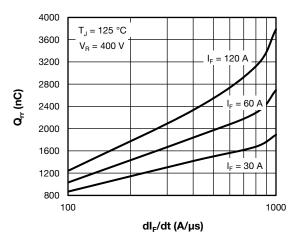


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt

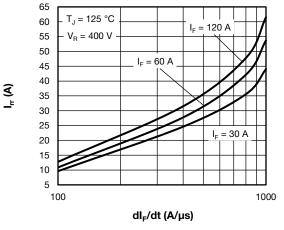
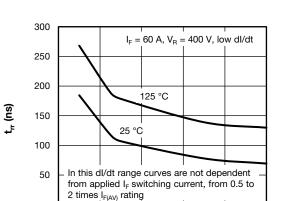


Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt

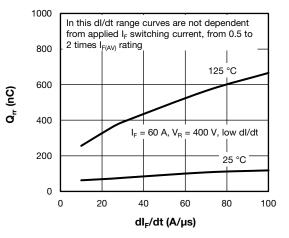




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Fig. 10 - Typical Reverse Recovery Time vs. dl_F/dt





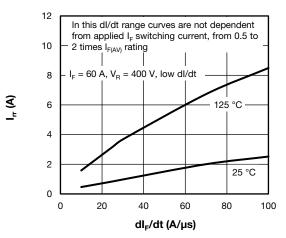


Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt

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VS-A5PH6006L-N3

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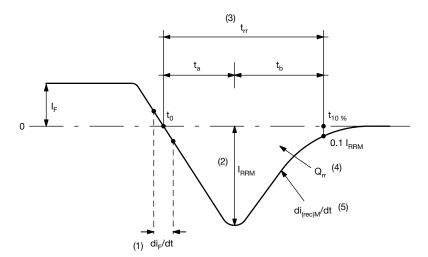


Fig. 13 - Reverse Recovery Waveform and Definitions

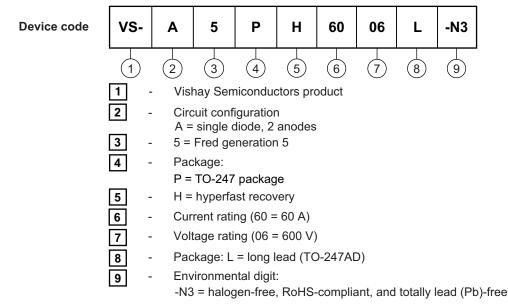
Notes

- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RRM}
- $^{(4)}~~Q_{rr}$ area under curve defined by t_0 and $t_{10~\%}$

$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t) dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-A5PH6006L-N3	25	500	Antistatic plastic tube			
	20	000				

LINKS TO RELATED DOCUMENTS					
Dimensions	<u>ww</u>	w.vishay.com/doc?95626			
Part marking information www.vishay.com/doc?95007					
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TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

(2, 52, 51) (4) Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	INCHES		
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D2	0.51	1.30	0.020	0.051		
E	15.29	15.87	0.602	0.625	3	
E1	13.46	-	0.53	-		
е	5.46	BSC	0.215	5 BSC		
ØК	0.2	254	0.0	010		
L	19.81	20.32	0.780	0.800		
L1	3.71	4.29	0.146	0.169		
ØР	3.56	3.66	0.14	0.144		
Ø P1	-	6.98	-	0.275		
Q	5.31	5.69	0.209	0.224		
R	4.52	5.49	0.178	0.216		
S	5.51 BSC		0.217	' BSC		

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

- ⁽³⁾ Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- ⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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